

PNP SILICON PLANAR MEDIUM POWER TRANSISTORS IN SOT223

Features

- $I_C = -1A$ Continuous Collector Current
- Low Saturation Voltage $V_{CE(sat)} < -500mV @ -0.5A$
- Gain groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary NPN types: BCP54, 55 and 56
- **Lead-Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Devices (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

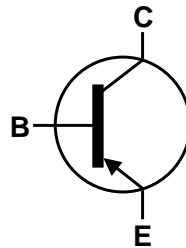
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (Approximate)

Applications

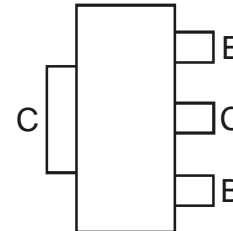
- Medium Power Switching or Amplification Applications
- AF driver and output stages

SOT223



Top View

Device Symbol

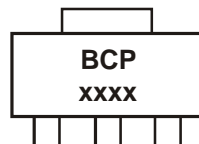
Top View
Pin-Out

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCP51TA	BCP 51	7	12	1,000
BCP5110TA	BCP 5110	7	12	1,000
BCP5116TA	BCP 5116	7	12	1,000
BCP5116TC	BCP 5116	13	12	4,000
BCP52TA	BCP 52	7	12	1,000
BCP5210TA	BCP 5210	7	12	1,000
BCP5216TA	BCP 5216	7	12	1,000
BCP53TA	BCP 53	7	12	1,000
BCP5310TA	BCP 5310	7	12	1,000
BCP5316TA	BCP 5316	7	12	1,000
BCP5316TC	BCP 5316	13	12	4,000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website <http://www.diodes.com>

Marking Information



BCP = Product Type Marking Code, Line 1.
xxxx = Product Type Marking Code, Line 2 as follows:

BCP51 = 51
BCP5110 = 5110
BCP5116 = 5116

BCP52 = 52
BCP5210 = 5210
BCP5216 = 5216

BCP53 = 53
BCP5310 = 5310
BCP5316 = 5316

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

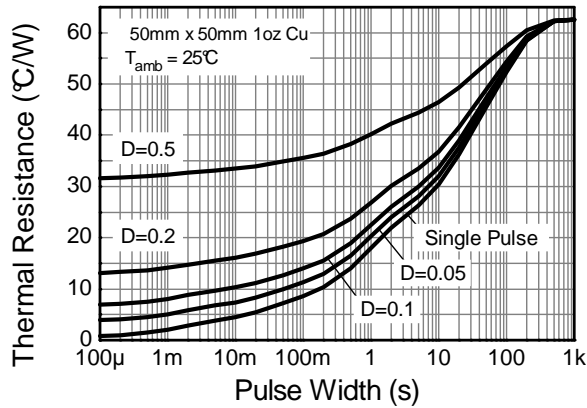
Characteristic	Symbol	BCP51	BCP52	BCP53	Unit
Collector-Base Voltage	V_{CBO}	-45	-60	-100	V
Collector-Emitter Voltage	V_{CEO}	-45	-60	-80	V
Emitter-Base Voltage	V_{EBO}		-5		V
Continuous Collector Current	I_C		-1		A
Peak Pulse Collector Current	I_{CM}		-2		
Continuous Base Current	I_B		-100		mA
Peak Pulse Base Current	I_{BM}		-200		

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

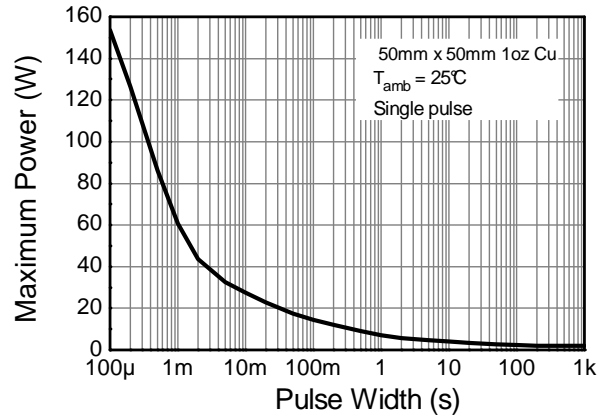
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_D	2	W
Thermal Resistance, Junction to Ambient (Note 4)	$R_{\theta JA}$	62	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Leads (Note 5)	$R_{\theta JL}$	19.4	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

- Notes:
4. For a device surface mounted on 50mm X 50mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 5. Thermal resistance from junction to solder-point (at the end of the collector lead).

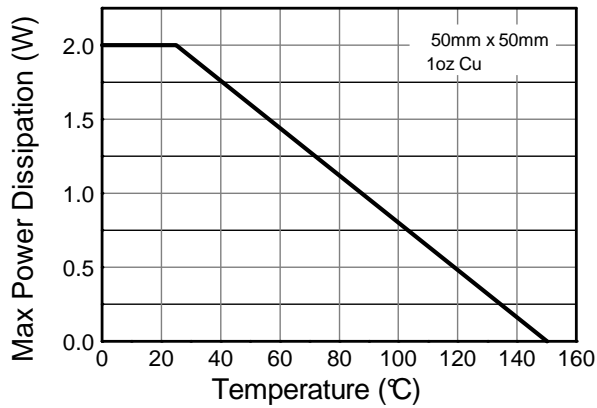
Thermal Characteristics



Transient Thermal Impedance



Pulse Power Dissipation

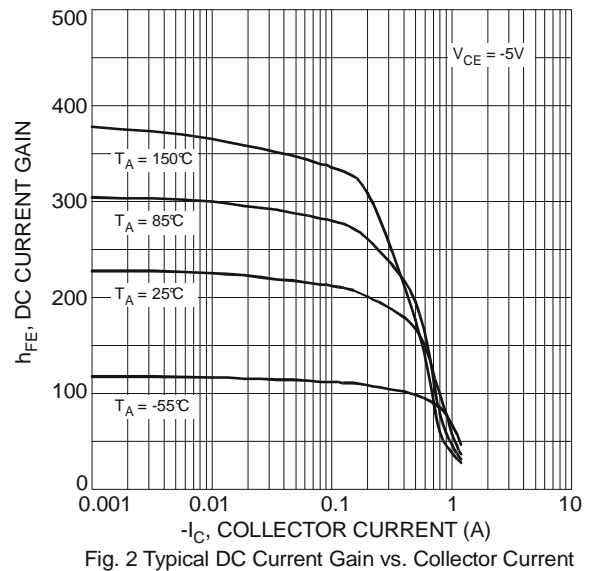
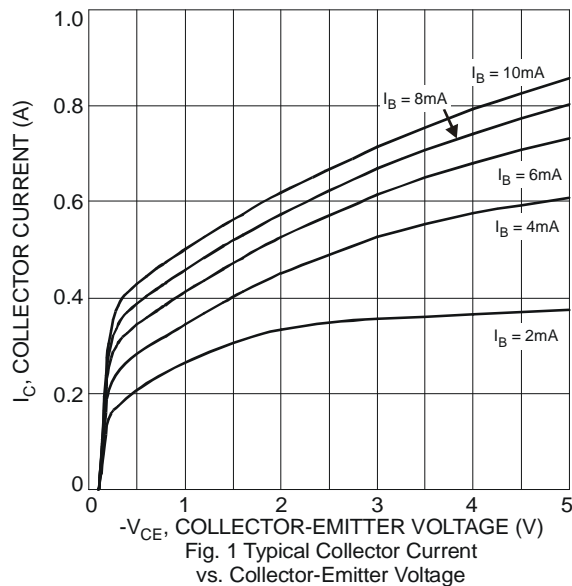


Derating Curve

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCP51	BV_{CBO}	-45	-	-	V	$I_C = -100\mu\text{A}$
	BCP52		-60				
	BCP53		-100				
Collector-Emitter Breakdown Voltage (Note 6)	BCP51	BV_{CEO}	-45	-	-	V	$I_C = -10\text{mA}$
	BCP52		-60				
	BCP53		-80				
Emitter-Base Breakdown Voltage		BV_{EBO}	-5	-	-	V	$I_E = -10\mu\text{A}$
Collector Cut-off Current		I_{CBO}	-	-	-0.1 -20	μA	$V_{CB} = -30\text{V}$ $V_{CB} = -30\text{V}, T_A = 150^\circ\text{C}$
Emitter Cut-off Current		I_{EBO}	-	-	-20	nA	$V_{EB} = -4\text{V}$
Static Forward Current Transfer Ratio (Note 6)	All versions	h_{FE}	25	-	-	-	$I_C = -5\text{mA}, V_{CE} = -2\text{V}$ $I_C = -150\text{mA}, V_{CE} = -2\text{V}$ $I_C = -500\text{mA}, V_{CE} = -2\text{V}$
			40	-	250		
	25		-	-			
	10 gain grp		63	-	160		
	16 gain grp		100	-	250	$I_C = -150\text{mA}, V_{CE} = -2\text{V}$	
Collector-Emitter Saturation Voltage (Note 6)		$V_{CE(sat)}$	-	-	-0.5	V	$I_C = -500\text{mA}, I_B = -50\text{mA}$
Base-Emitter Turn-On Voltage (Note 6)		$V_{BE(on)}$	-	-	-1.0	V	$I_C = -500\text{mA}, V_{CE} = -2\text{V}$
Transition Frequency		f_r	150	-	-	MHz	$I_C = -50\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$
Output Capacitance		C_{obo}	-	-	25	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$

Notes: 6. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.



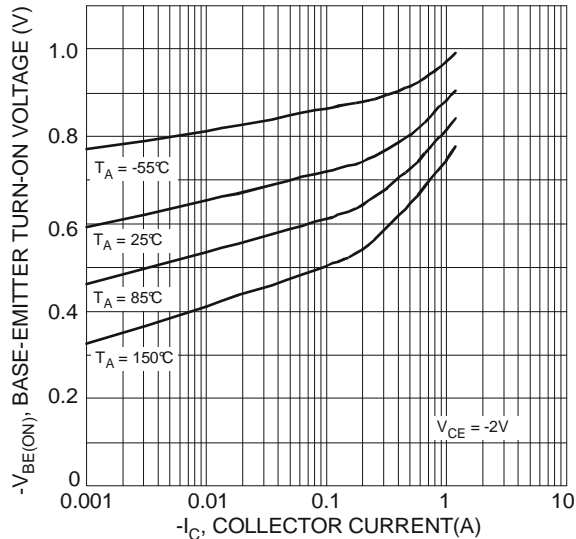


Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

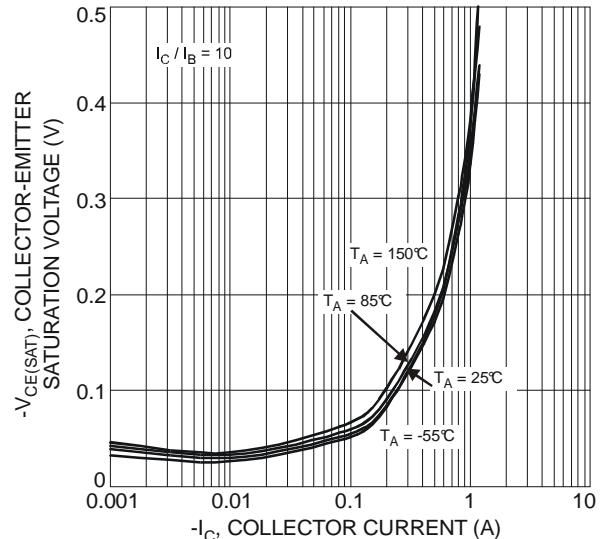


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

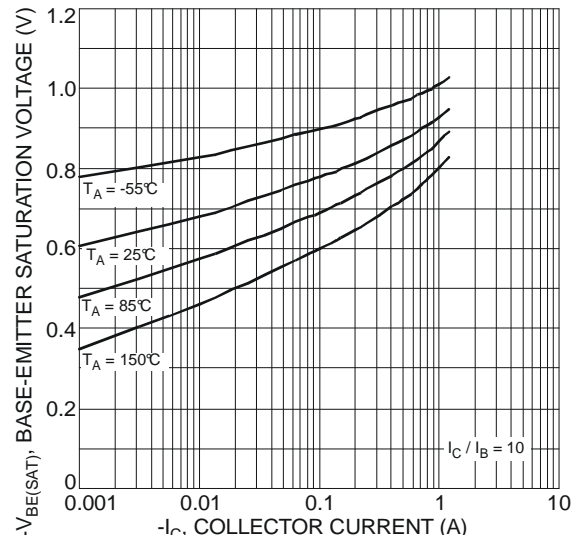


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

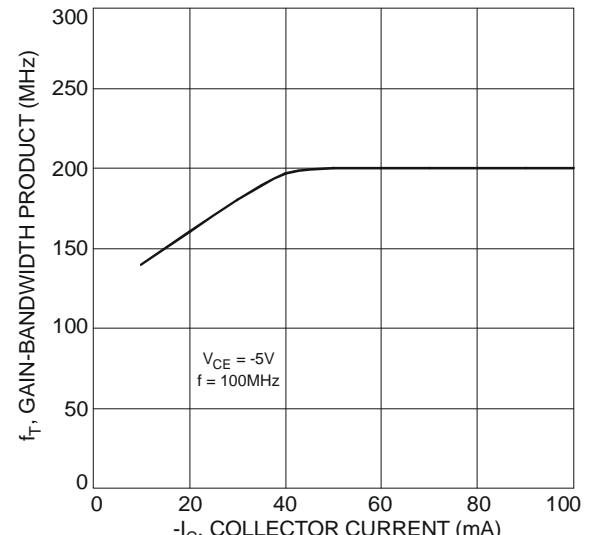


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current

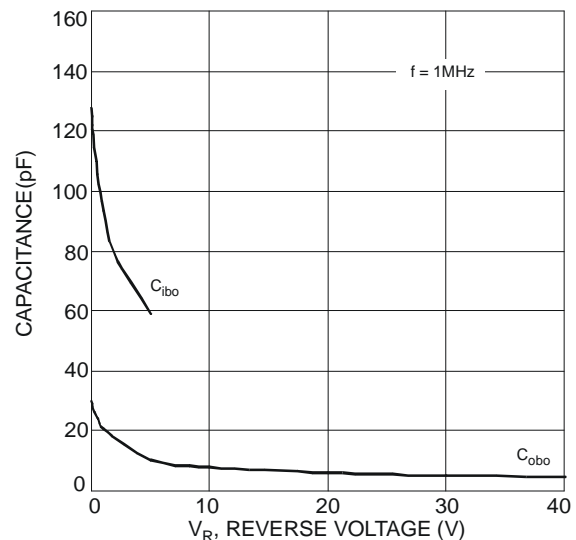
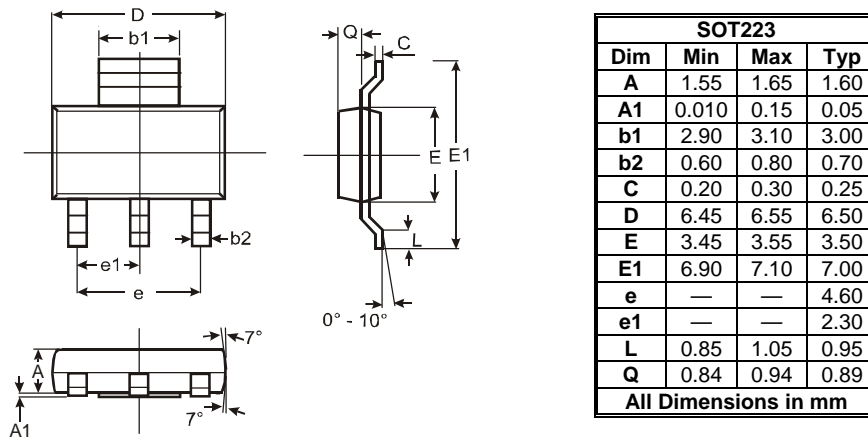
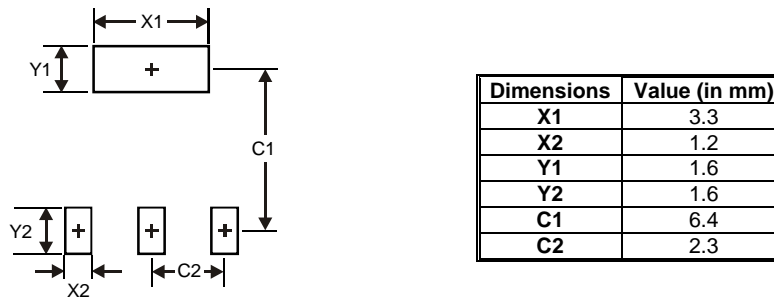


Fig. 7 Typical Capacitance Characteristics

Package Outline Dimensions



Suggested Pad Layout



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